

A2 temperature at or slightly below a thin-film glass transition temperature of said metal containing resistance variable material.

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A3 35. (Amended) The element of claim 34 wherein said glass has a germanium molar concentration number greater than about 0.23.

36. (Amended) The element of claim 34 wherein said glass has a mean coordination number of at least about 2.46.

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A4 40. (Amended) The element of claim 39 wherein said metal is silver.

41. (Amended) The element of claim 39 wherein said annealed metal containing resistance variable material comprises a germanium-selenide glass.

42. (Amended) The element of claim 41 wherein said germanium-selenide glass has a germanium molar concentration number of greater than about 0.23.

43. (Amended) The element of claim 39 wherein said annealed metal containing resistance variable material has a mean coordination number of at least about 2.46.

44. (Amended) The element of claim 39 wherein said annealed metal containing resistance variable material comprises a silver doped germanium-selenide.

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A5 46. (Amended) The element of claim 45 wherein said metal comprises silver.

47. (Amended) The element of claim 45 wherein said annealed metal containing resistance variable material comprises a germanium-selenide glass.

AS 48. (Amended) The element of claim 47 wherein said germanium-selenide glass has a germanium molar concentration number of greater than about 0.23.

49. (Amended) The element of claim 45 wherein said annealed metal containing resistance variable material has a mean coordination number of at least about 2.46.

50. (Amended) The element of claim 45 wherein said annealed metal containing resistance variable material comprises a silver doped germanium-selenide.

51. (Amended) A computer device having a memory, said memory comprising:

an annealed metal containing resistance variable material having increased rigidity.

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A6 58. (Amended) The element of claim 57 wherein said annealed resistance variable material comprises silver.

59. (Amended) The element of claim 57 wherein said annealed resistance variable material comprises a germanium-selenide glass.

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